

# KF353

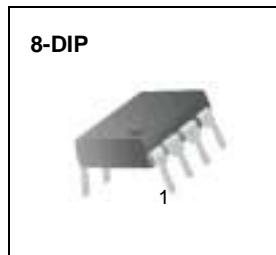
## Dual Operational Amplifier (JFET)

### Features

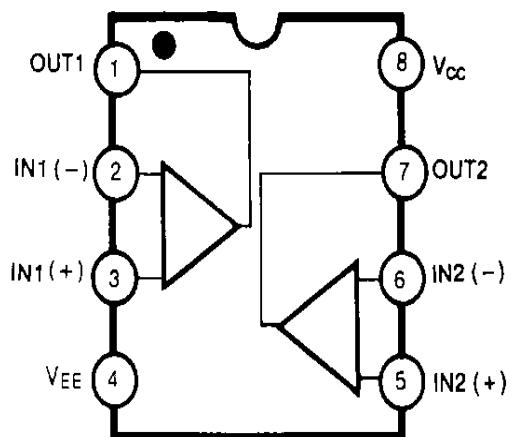
- Internally trimmed offset voltage: 10mV
- Low input bias current: 50pA
- Wide gain bandwidth: 4MHz
- High slew rate: 13V/ $\mu$ s
- High Input impedance:  $10^{12}\Omega$

### Description

The KF353 is a JFET input operational amplifier with an internally compensated input offset voltage. The JFET input device provides wide bandwidth, low input bias currents and offset currents.

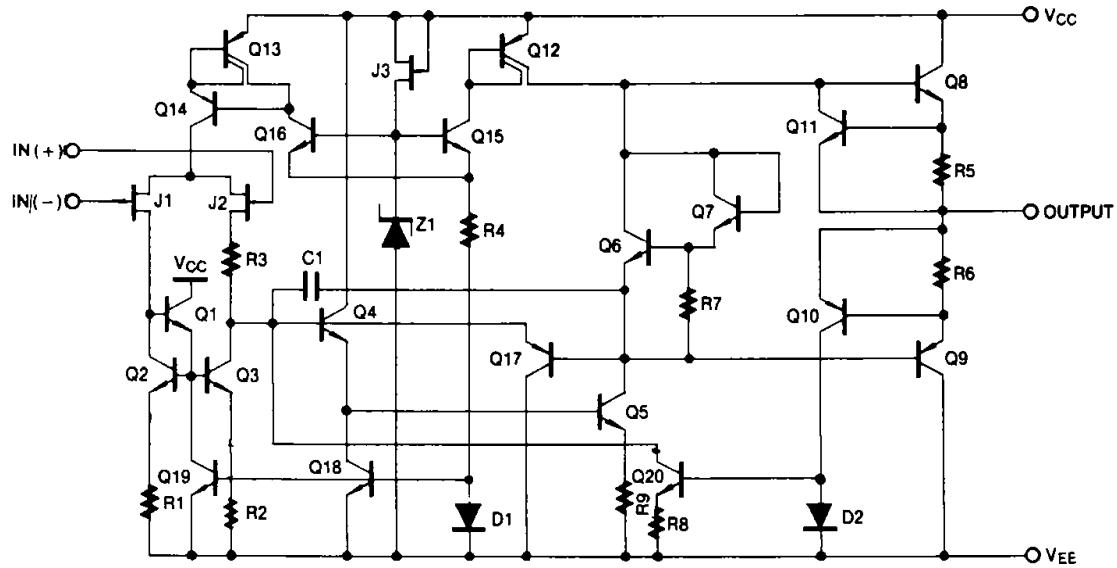


### Internal Block Diagram



## Schematic Diagram

(One Section Only)



## Absolute Maximum Ratings

| Parameter                     | Symbol               | Value      | Unit |
|-------------------------------|----------------------|------------|------|
| Power Supply Voltage          | V <sub>CC</sub>      | $\pm 18$   | V    |
| Differential Input Voltage    | V <sub>I(DIFF)</sub> | 30         | V    |
| Input Voltage Range           | V <sub>I</sub>       | $\pm 15$   | V    |
| Output Short Circuit Duration | -                    | Continuous | -    |
| Power Dissipation             | P <sub>D</sub>       | 500        | mW   |
| Operating Temperature Range   | T <sub>OPR</sub>     | 0 ~ +70    | °C   |
| Storage Temperature Range     | T <sub>STG</sub>     | -65 ~ +150 | °C   |

## Electrical Characteristics

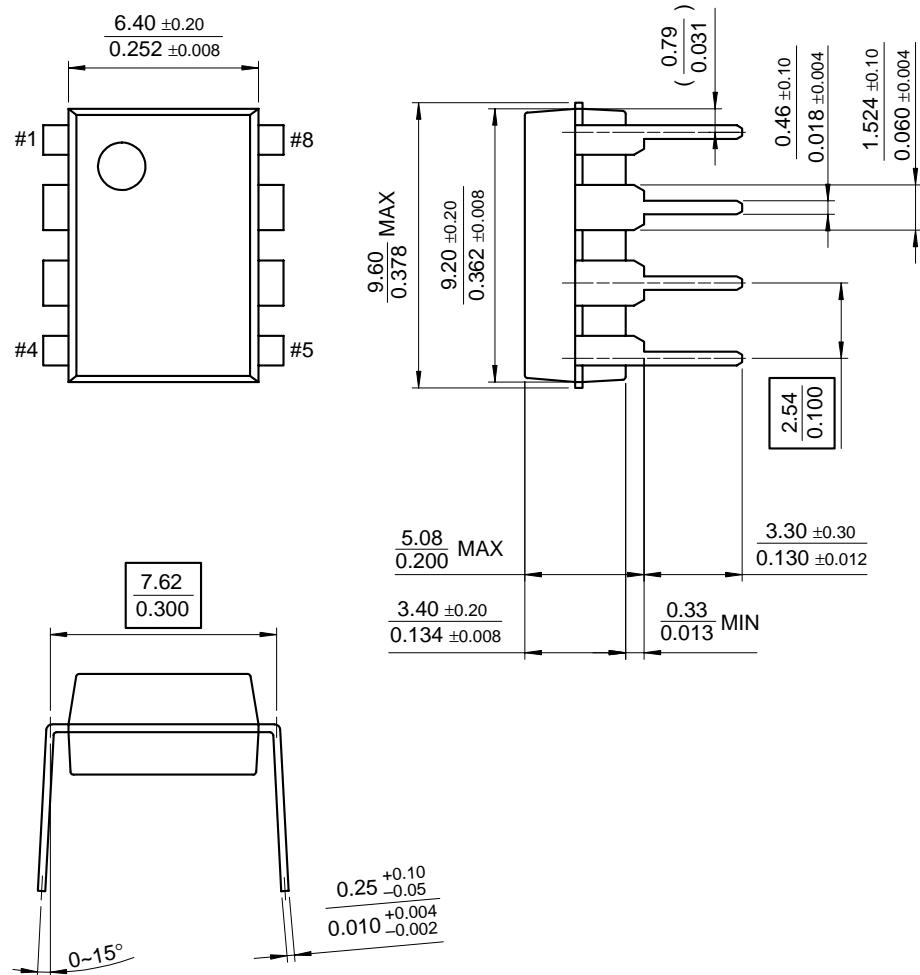
(V<sub>CC</sub> = +15V, V<sub>EE</sub> = -15V, T<sub>A</sub> = 25 °C, unless otherwise specified)

| Parameter                      | Symbol               | Conditions                                       | Min.                        | Typ.             | Max. | Unit   |        |
|--------------------------------|----------------------|--|-----------------------------|------------------|------|--------|--------|
| Input Offset Voltage           | V <sub>IO</sub>      | R <sub>S</sub> =10KΩ                             | -                           | 5.0              | 10   | mV     |        |
|                                |                      | 0 °C≤T <sub>A</sub> ≤+70 °C                      | -                           | -                | -    |        |        |
| Input Offset Voltage Drift     | ΔV <sub>IO</sub> /ΔT | R <sub>S</sub> =10KΩ                             | 0 °C≤T <sub>A</sub> ≤+70 °C | -                | 10   | -      | μV/ °C |
| Input Offset Current           | I <sub>IO</sub>      |  | -                           | 25               | 100  | pA     |        |
| Input Bias Current             | I <sub>BIAS</sub>    |  | 0 °C≤T <sub>A</sub> ≤+70 °C | -                | 4    | nA     |        |
|                                |                      |  | 0 °C≤T <sub>A</sub> ≤+70 °C | -                | 50   | 200    | pA     |
| Input Resistance               | R <sub>I</sub>       | -  | -                           | 10 <sup>12</sup> | -    | Ω      |        |
| Large Signal Voltage Gain      | G <sub>V</sub>       | V <sub>O(P-P)</sub> = ±10V                       | 25                          | 100              | -    | V/mV   |        |
|                                |                      | R <sub>L</sub> = 2KΩ 0 °C≤T <sub>A</sub> ≤+70 °C | 15                          | -                | -    |        |        |
| Output Voltage Swing           | V <sub>O(P-P)</sub>  | R <sub>L</sub> = 10KΩ                            | ±12                         | ±13.5            | -    | V      |        |
| Input Voltage Range            | V <sub>I(R)</sub>    | -  | ±11                         | ±15/-12          | -    | V      |        |
| Common Mode Rejection Ratio    | CMRR                 | R <sub>S</sub> ≤ 10KΩ                            | 70                          | 100              | -    | dB     |        |
| Power Supply Rejection Ratio   | PSRR                 | R <sub>S</sub> ≤ 10KΩ                            | 70                          | 100              | -    | dB     |        |
| Power Supply Current           | I <sub>CC</sub>      | -  | -                           | 3.6              | 6.5  | mA     |        |
| Slew Rate                      | SR                   | G <sub>V</sub> = 1                               | -                           | 13               | -    | V/μS   |        |
| Gain-Bandwidth Product         | GBW                  | -  | -                           | 4                | -    | MHz    |        |
| Channel Separation             | CS                   | f = 1Hz ~ 20KHz<br>(Input referenced)            | -                           | 120              | -    | dB     |        |
| Equivalent Input Noise Voltage | V <sub>NI</sub>      | R <sub>S</sub> = 100Ω<br>f = 1KHz                | -                           | 16               | -    | nV/√Hz |        |
| Equivalent Input Noise Current | I <sub>NI</sub>      | f = 1KHz   | -                           | 0.01             | -    | pA/√Hz |        |

## Mechanical Dimensions

### Package

**8-DIP**



## Ordering Information

| Product Number | Package | Operating Temperature |
|----------------|---------|-----------------------|
| KF353          | 8-DIP   | 0 ~ + 70°C            |

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